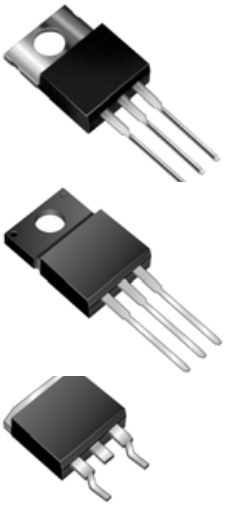
Dual Schottky Barrier Rectifiers
Reverse Voltage 200 Volts Forward Current 30.0 Amperes

Features

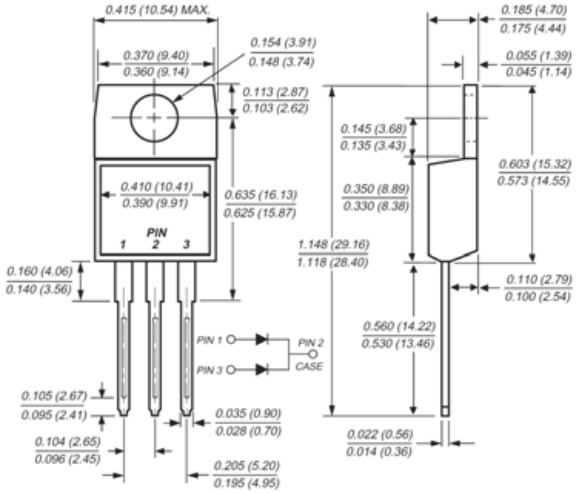
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Dual rectifier construction, positive center tap
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Guardring for overvoltage protection
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case



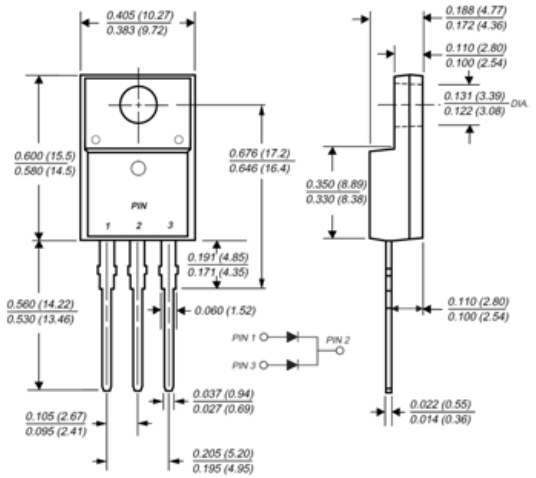
Mechanical Data

- Case: JEDEC TO-220AB, TO-220F , TO-263AB molded plastic body
- Terminals: Plated leads, solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting Position: Any
- Mounting Torque: 10 in-lbs maximum
- Weight: 0.08 ounce, 2.24 grams

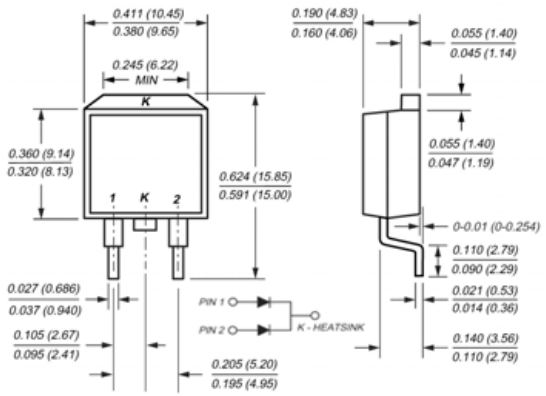
TO-220AB



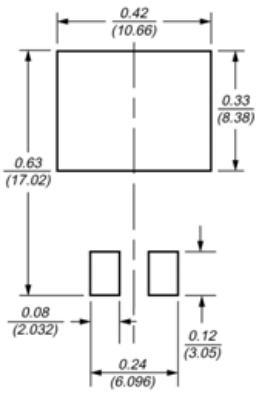
TO-220F



TO-263AB(D²PAK)



Mounting Pad Layout TO-263AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	200	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	140	V
I_O	Average rectified output current	30	A
I_{FSM}	Non-Repetitive peak forward surge current 8.3ms half sine wave	200	A
P_D	Power dissipation	2	W
$R_{\Theta JA}$	Thermal resistance from junction to ambient	50	℃/W
T_j	Junction temperature	125	℃
T_{stg}	Storage temperature	-55~+150	℃

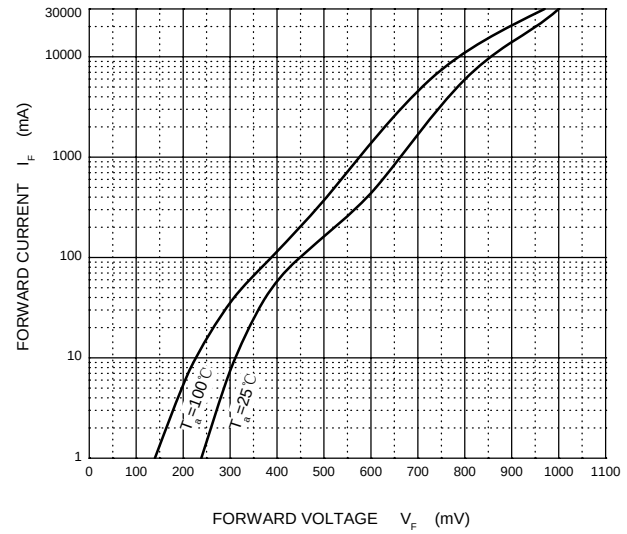
ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	I_R=1mA	200			V
Reverse current	I_R	V_R=200V			0.1	mA
Forward voltage	V_{F1}	I_F=15A			0.95	V
	V_{F2}*	I_F=30A			1.1	V
Typical total capacitance	C_{tot}	V_R=4V,f=1MHz		800		pF

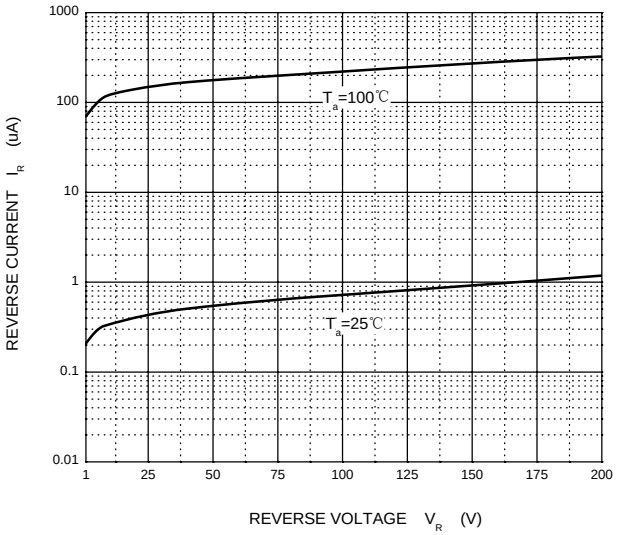
*Pulse test

Rating and Characteristic Curves

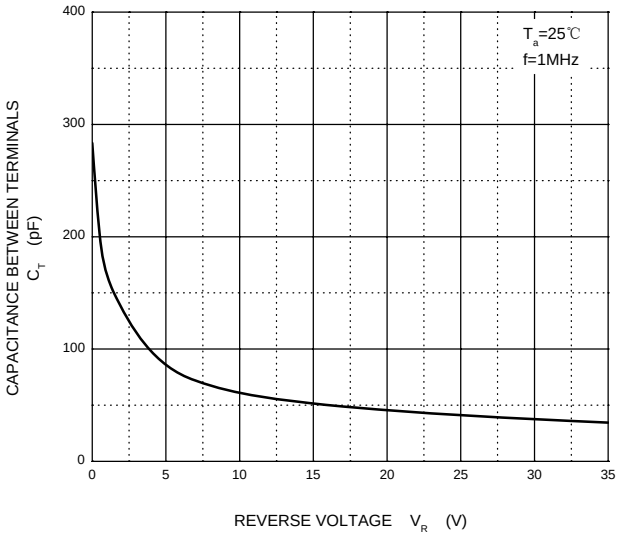
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve